

Serial No.: 09/902,429

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AF/2800

Case No: F0588

PATENT

#6 response

J/E

M. Brunson

12/12/02



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

RECEIVED  
DEC-4 2002  
TC 2800 MAIL ROOM

In re application of: Qi Xiang

Serial No.: 09/902,429

Filing Date: July 10, 2001

For: SILICON ON INSULATOR FIELD EFFECT TRANSISTOR WITH  
HETEROJUNCTION GATE.

Examiner: Laura M. Schillinger

Art Unit: 2813

**AFTER FINAL REPLY  
EXPEDITED HANDLING REQUESTED**

**Box AF  
Assistant Commissioner for Patents  
Washington, D.C. 20231**

**RESPONSE TO OFFICE ACTION DATED SEPTEMBER 25, 2002**

Examiner:

The applicants respectfully request favorable reconsideration of the application  
in view of the following comments.

**REMARKS**

Claims 1-14 and 21-27 are presently under consideration. Favorable  
reconsideration of the application is respectfully requested.